

## Molding Type Module IGBT, 2-in-1 Package, 1200 V, 400 A



Double INT-A-PAK

### FEATURES

- Low  $V_{CE(on)}$  trench IGBT technology
- 10  $\mu$ s short circuit capability
- $V_{CE(on)}$  with positive temperature coefficient
- Maximum junction temperature 175 °C
- Low inductance case
- Fast and soft reverse recovery antiparallel FWD
- Isolated copper baseplate using DCB (Direct Copper Bonding) technology
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

### PRODUCT SUMMARY

$V_{CES}$	1200 V
$I_C$ at $T_C = 80$ °C	400 A
$V_{CE(on)}$ (typical) at $I_C = 400$ A, 25 °C	1.90 V
Speed	8 kHz to 30 kHz
Package	Double INT-A-PAK
Circuit	Half bridge

### TYPICAL APPLICATIONS

- Inverter for motor drive
- AC and DC servo drive amplifier
- Uninterruptible power supply (UPS)

### DESCRIPTION

Vishay's IGBT power module provides ultralow conduction loss as well as short circuit ruggedness. It is designed for applications such as general inverters and UPS.

### ABSOLUTE MAXIMUM RATINGS ( $T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Collector to emitter voltage	$V_{CES}$		1200	V
Gate to emitter voltage	$V_{GES}$		$\pm 30$	
Collector current	$I_C$	$T_C = 25$ °C	750	A
		$T_C = 80$ °C	400	
Pulsed collector current	$I_{CM}$	$t_p = 1$ ms	800	
Diode continuous forward current	$I_F$		400	
Diode maximum forward current	$I_{FM}$	$t_p = 1$ ms	800	
Maximum power dissipation	$P_D$	$T_J = 175$ °C	2344	
RMS isolation voltage	$V_{ISOL}$	$f = 50$ Hz, $t = 1$ min	2500	V
Operating junction temperature range	$T_J$		-40 to +150	°C



<b>IGBT ELECTRICAL SPECIFICATIONS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Collector to emitter breakdown voltage	$V_{(BR)CES}$	$T_J = 25\text{ }^\circ\text{C}$	1200	-	-	V
Collector to emitter voltage	$V_{CE(on)}$	$V_{GE} = 15\text{ V}, I_C = 400\text{ A}, T_J = 25\text{ }^\circ\text{C}$	-	1.90	2.35	
		$V_{GE} = 15\text{ V}, I_C = 400\text{ A}, T_J = 125\text{ }^\circ\text{C}$	-	2.30	-	
Gate to emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}, I_C = 20\text{ mA}, T_J = 25\text{ }^\circ\text{C}$	5.0	5.9	7.5	
Collector cut-off current	$I_{CES}$	$V_{CE} = V_{CES}, V_{GE} = 0\text{ V}, T_J = 25\text{ }^\circ\text{C}$	-	-	5.0	mA
Gate to emitter leakage current	$I_{GES}$	$V_{GE} = V_{GES}, V_{CE} = 0\text{ V}, T_J = 25\text{ }^\circ\text{C}$	-	-	400	nA

<b>SWITCHING CHARACTERISTICS</b>						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-on delay time	$t_{d(on)}$	$V_{CC} = 600\text{ V}, I_C = 400\text{ A}, R_g = 1.4\text{ }\Omega, V_{GE} = \pm 15\text{ V}, T_J = 25\text{ }^\circ\text{C}$	-	187	-	ns
Rise time	$t_r$		-	57	-	
Turn-off delay time	$t_{d(off)}$		-	180	-	
Fall time	$t_f$		-	149	-	
Turn-on switching loss	$E_{on}$	$V_{CC} = 600\text{ V}, I_C = 400\text{ A}, R_g = 1.4\text{ }\Omega, V_{GE} = \pm 15\text{ V}, T_J = 125\text{ }^\circ\text{C}$	-	19.9	-	mJ
Turn-off switching loss	$E_{off}$		-	18.8	-	
Turn-on delay time	$t_{d(on)}$		-	189	-	
Rise time	$t_r$		-	58	-	
Turn-off delay time	$t_{d(off)}$	$V_{CC} = 600\text{ V}, I_C = 400\text{ A}, R_g = 1.4\text{ }\Omega, V_{GE} = \pm 15\text{ V}, T_J = 125\text{ }^\circ\text{C}$	-	187	-	ns
Fall time	$t_f$		-	220	-	
Turn-on switching loss	$E_{on}$		-	31.2	-	
Turn-off switching loss	$E_{off}$		-	23.4	-	
Input capacitance	$C_{ies}$	$V_{GE} = 0\text{ V}, V_{CE} = 30\text{ V}, f = 1.0\text{ MHz}$	-	51.2	-	nF
Output capacitance	$C_{oes}$		-	1.84	-	
Reverse transfer capacitance	$C_{res}$		-	1.28	-	
SC data	$I_{SC}$	$t_p \leq 10\text{ }\mu\text{s}, V_{GE} = 15\text{ V}, T_J = 125\text{ }^\circ\text{C}, V_{CC} = 900\text{ V}, V_{CEM} \leq 1200\text{ V}$	-	3560	-	A
Internal gate resistance	$R_{gint}$		-	0.59	-	$\Omega$
Stray inductance	$L_{CE}$		-	-	18	nH
Module lead resistance, terminal to chip	$R_{CC'+EE'}$		-	0.32	-	m $\Omega$

<b>DIODE ELECTRICAL SPECIFICATIONS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Diode forward voltage	$V_F$	$I_F = 400\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$	-	1.80	2.20	V
			$T_J = 125\text{ }^\circ\text{C}$	-	1.85	-	
Recovery charge	$Q_{rr}$	$I_F = 400\text{ A}, V_R = 600\text{ V}, R_g = 4.1\text{ }\Omega, V_{GE} = -15\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	26	-	$\mu\text{C}$
			$T_J = 125\text{ }^\circ\text{C}$	-	49	-	
Peak reverse recovery current	$I_{rr}$	$I_F = 400\text{ A}, V_R = 600\text{ V}, R_g = 4.1\text{ }\Omega, V_{GE} = -15\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	212	-	A
			$T_J = 125\text{ }^\circ\text{C}$	-	281	-	
Reverse recovery energy	$E_{rec}$	$I_F = 400\text{ A}, V_R = 600\text{ V}, R_g = 4.1\text{ }\Omega, V_{GE} = -15\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	23.4	-	mJ
			$T_J = 125\text{ }^\circ\text{C}$	-	33.8	-	



THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction temperature	$T_J$ max.		-	-	175	°C
Operating junction temperature range	$T_{Jop}$		-40	-	150	
Storage temperature range	$T_{STG}$		-40	-	125	
Junction to case	IGBT	$R_{thJC}$	-	-	0.064	K/W
	Diode		-	-	0.098	
Case to sink	$R_{thCS}$	Conductive grease applied	-	0.032	-	
Mounting torque		Power terminal screw: M6	2.5 to 5.0			Nm
		Mounting screw: M6	3.0 to 5.0			
Weight			350			g

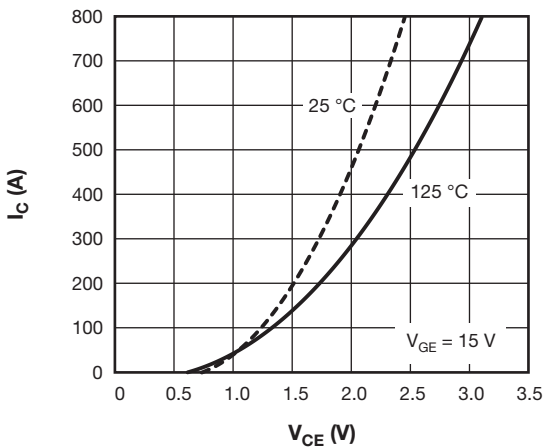


Fig. 1 - IGBT Output Characteristics

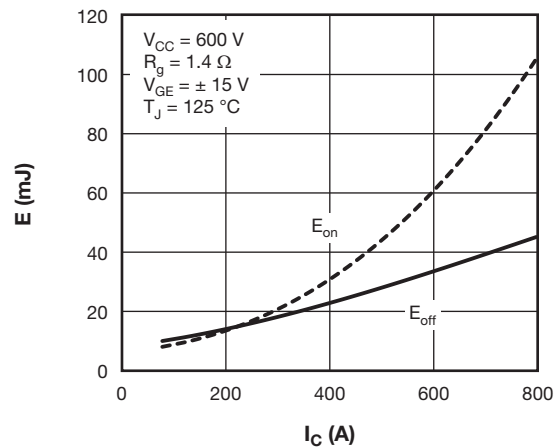


Fig. 3 - IGBT Switching Loss vs.  $I_C$

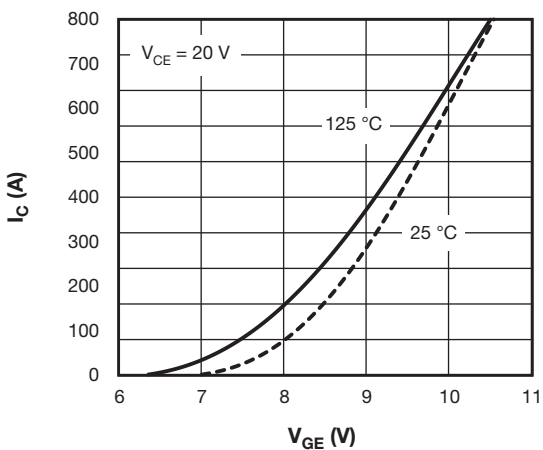


Fig. 2 - IGBT Transfer Characteristics

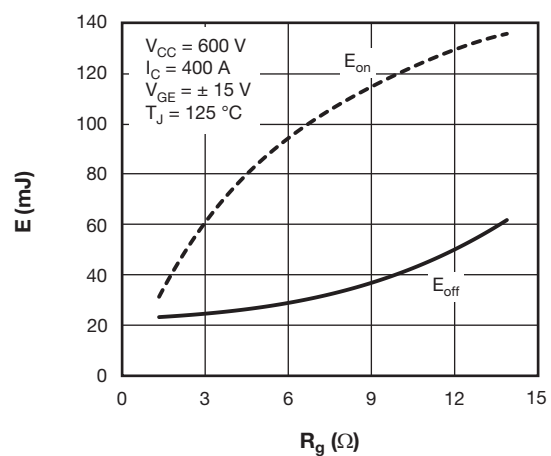


Fig. 4 - IGBT Switching Loss vs.  $R_g$

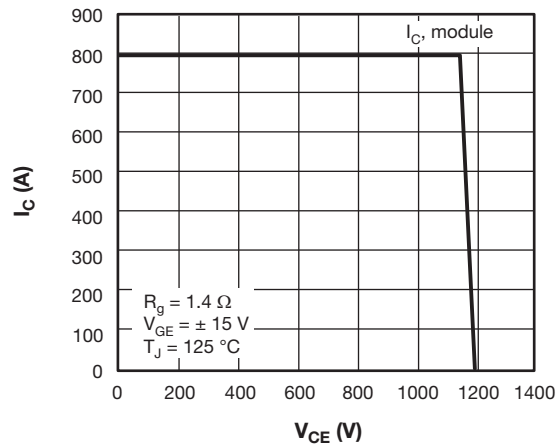


Fig. 5 - RBSOA

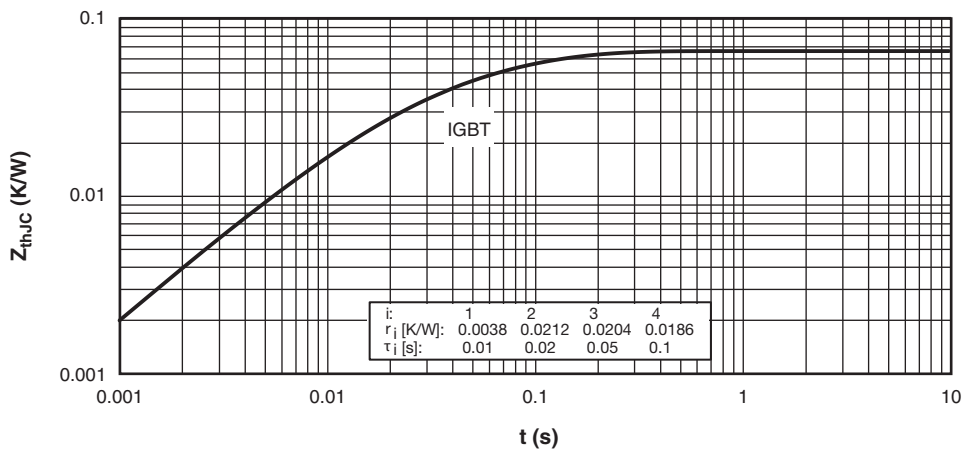


Fig. 6 - IGBT Transient Thermal Impedance

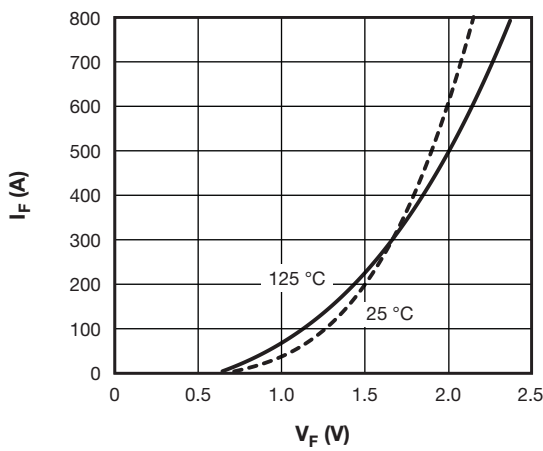


Fig. 7 - Diode Forward Characteristics

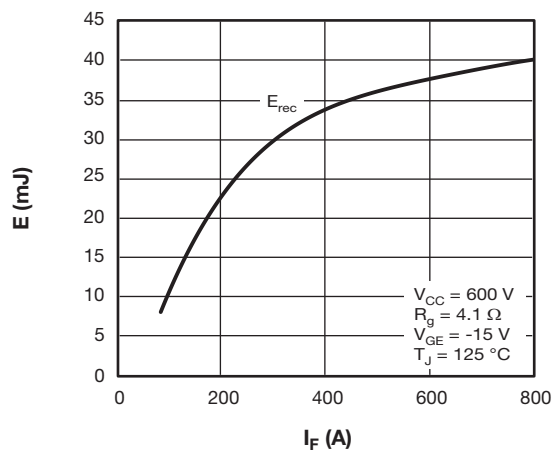


Fig. 8 - Diode Switching Loss vs. If

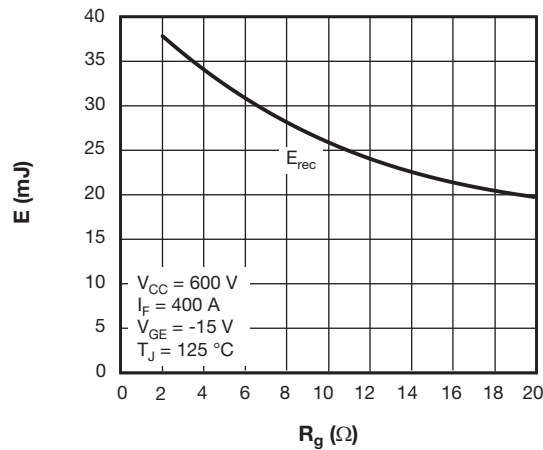


Fig. 9 - Diode Switching Loss vs.  $R_g$

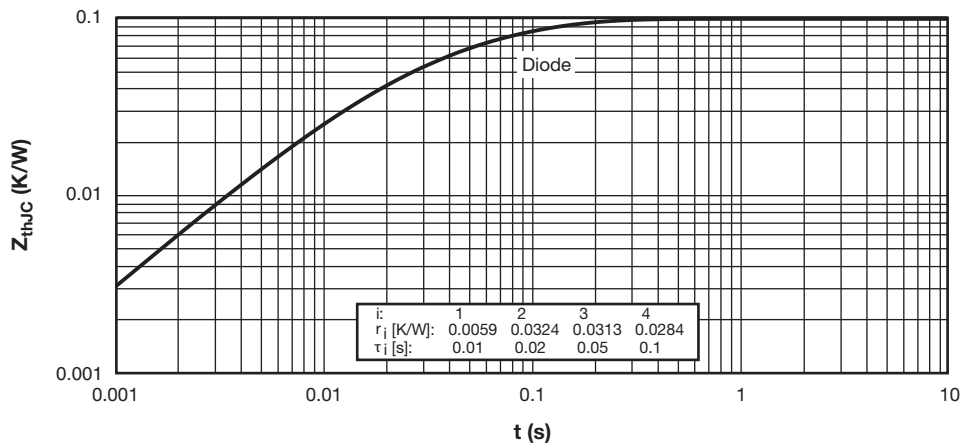
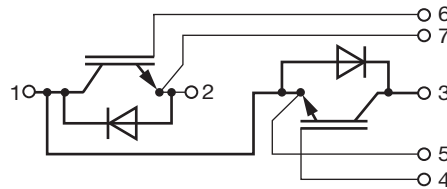


Fig. 10 - Diode Transient Thermal Impedances

**CIRCUIT CONFIGURATION**



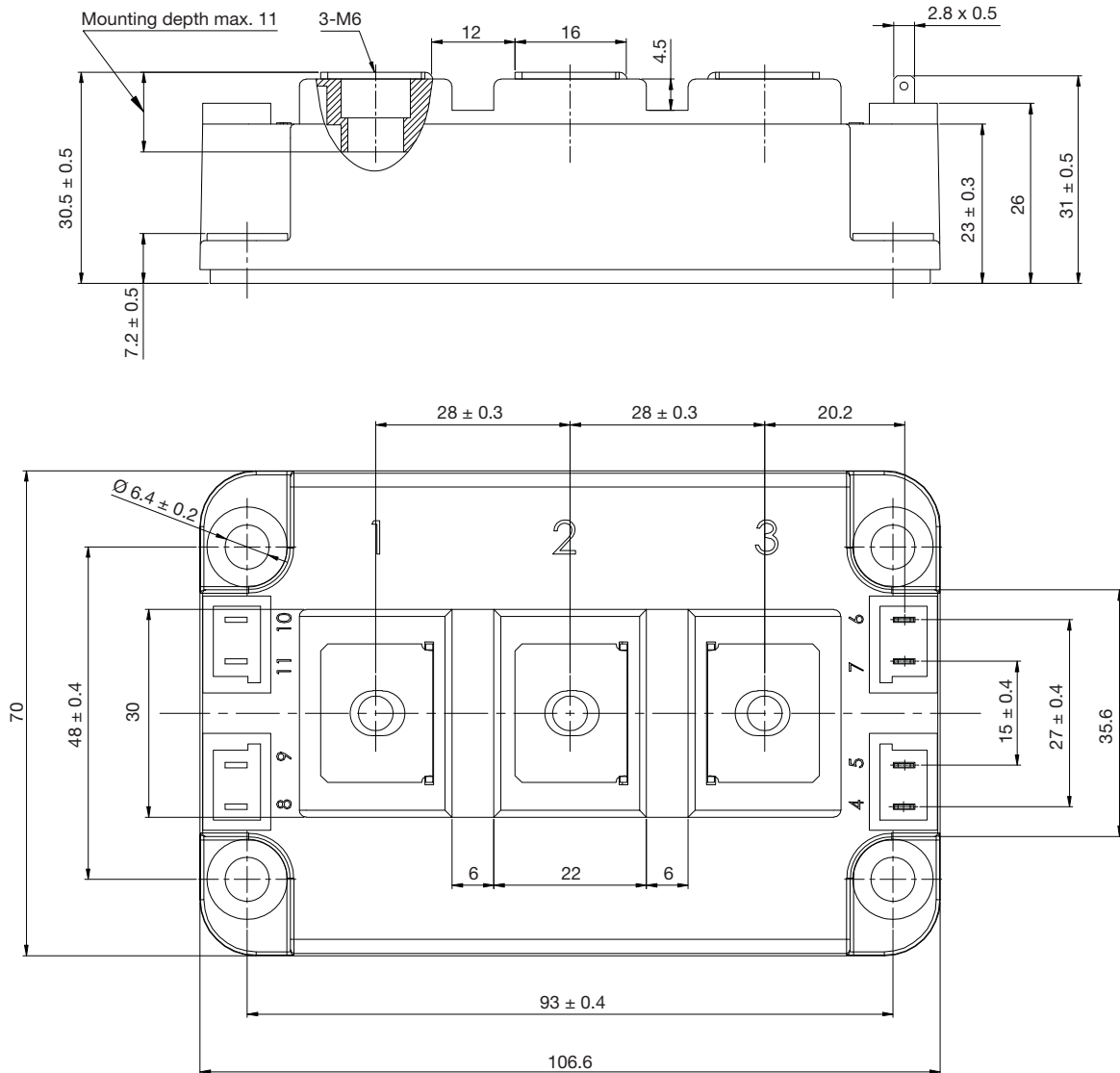
**LINKS TO RELATED DOCUMENTS**

Dimensions	<a href="http://www.vishay.com/doc?95538">www.vishay.com/doc?95538</a>
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## Double INT-A-PAK

**DIMENSIONS** in millimeters (inches)





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